

www.vishay.com

Vishay Semiconductors

Small Signal Fast Switching Diode



FEATURES

- Silicon epitaxial planar diode
- · Fast switching diodes
- AEC-Q101 qualified
- Base P/N-E3 RoHS-compliant, commercial grade



- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

MECHANICAL DATA

Case: SOD-123

Weight: approx. 10.3 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE						
PART	ORDERING CODE TYPE MARKING INTERNA		INTERNAL CONSTRUCTION	REMARKS		
1N4148W	1N4148W-E3-08 or 1N4148W-E3-18	A2	Single diade	Tape and reel		
	1N4148W-HE3-08 or 1N4148W-HE3-18	AZ	Single diode			

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	75	V	
Repetitive peak reverse voltage		V_{RRM}	100	V	
Average rectified current half wave rectification with resistive load ⁽¹⁾	f ≥ 50 Hz	I _{F(AV)}	150	mA	
Curan formand augment	t _p < 1 s	I _{FSM}	500	mA	
Surge forward current	t _p = 1 μs	I _{FSM}	2	А	
Power dissipation (1)		P _{tot}	350	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air (1)		R _{thJA}	357	K/W		
Junction temperature		T _j	150	°C		
Storage temperature range		T _{stg}	- 65 to + 150	°C		
Operating temperature range		Top	- 55 to + 150	°C		

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature.



Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I _F = 10 mA	V _F			1	V	
Forward voltage	I _F = 100 mA	V_{F}			1.2	V	
	V _R = 20 V	I _R			25	nA	
Leakage current	V _R = 75 V	I _R			5	μA	
Leakage current	V _R = 100 V	I_{R}			100	μΑ	
	V _R = 20 V, T _J = 150 °C	I _R			50	μA	
Diode capacitance	$V_F = V_R = 0 V$	C _D			4	pF	
Voltage rise when switching ON	Tested with 50 mA pulses, $t_p = 0.1 \mu s$, rise time < 30 ns, $f_p = (5 \text{ to } 100) \text{ kHz}$	V _{fr}			2.5	V	
Reverse recovery time	I_F = 10 mA, i_R = 1 mA, V_R = 6 V, R_L = 100 Ω	t _{rr}			4	ns	

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

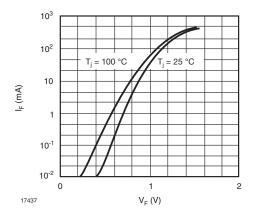


Fig. 1 - Forward Characteristics

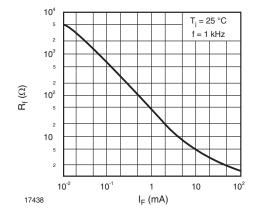


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

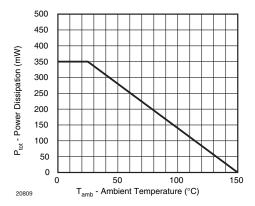


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

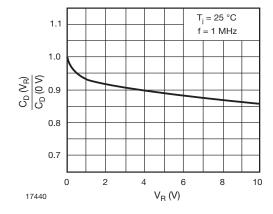


Fig. 4 - Relative Capacitance vs. Reverse Voltage



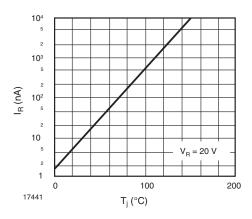


Fig. 5 - Leakage Current vs. Junction Temperature

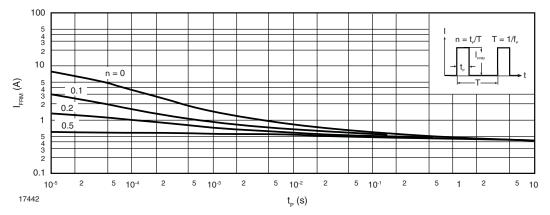
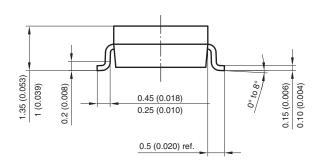


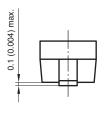
Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration



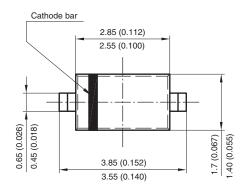
Vishay Semiconductors

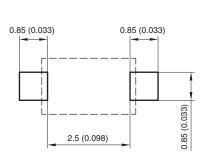
PACKAGE DIMENSIONS in millimeters (inches): SOD-123





Mounting Pad Layout





Rev. 4 - Date: 24. Sep. 2009 Document no.: S8-V-3910.01-001 (4) 17432



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.